

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Logic-level compatible
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

### 3. Applications

- DC-to-DC converters
- Battery management
- Low-side load-switch
- Switching circuits

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	30	V
V <sub>GS</sub>	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	17.3	А
Static chara	cteristics						
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 25 °C		-	7.7	9.1	mΩ
	resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10.1 A; T <sub>j</sub> = 25 °C		-	9.3	11.6	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



# 5. Pinning information

Table 2	. Pinning info	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source	_ف_ف_ف_	
3	S	source		D
4	G	gate	Ľ Ÿ	
5	D	drain		G C C
6	D	drain	— Цеееи	mbb076 S
7	D	drain		
8	D	drain	MLPAK33 (SOT8002-1)	

# 6. Ordering information

Table 3. Ordering information						
Type number						
	Name	Description	Version			
PXN9R0-30QL	MLPAK33	plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1			

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
PXN9R0-30QL	7AM

30 V, N-channel Trench MOSFET

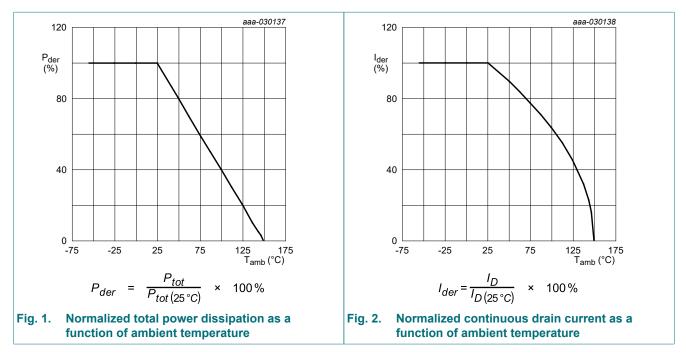
## 8. Limiting values

#### Table 5. Limiting values

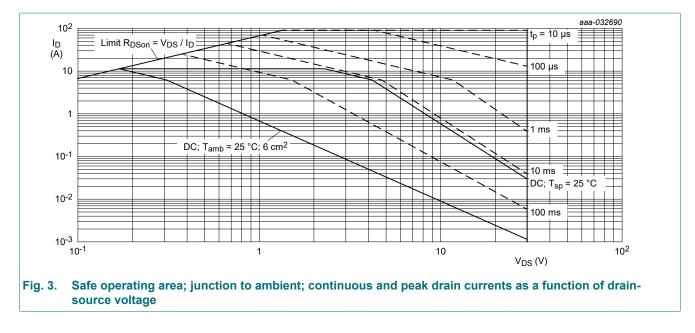
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	30	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	17.3	А
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	11.4	А
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	7.2	А
		V <sub>GS</sub> = 10 V; T <sub>sp</sub> = 25 °C		-	41.8	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	90	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	4.5	W
		T <sub>amb</sub> = 25 °C	[1]	-	1.9	W
		T <sub>sp</sub> = 25 °C		-	26	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.7	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



#### 30 V, N-channel Trench MOSFET

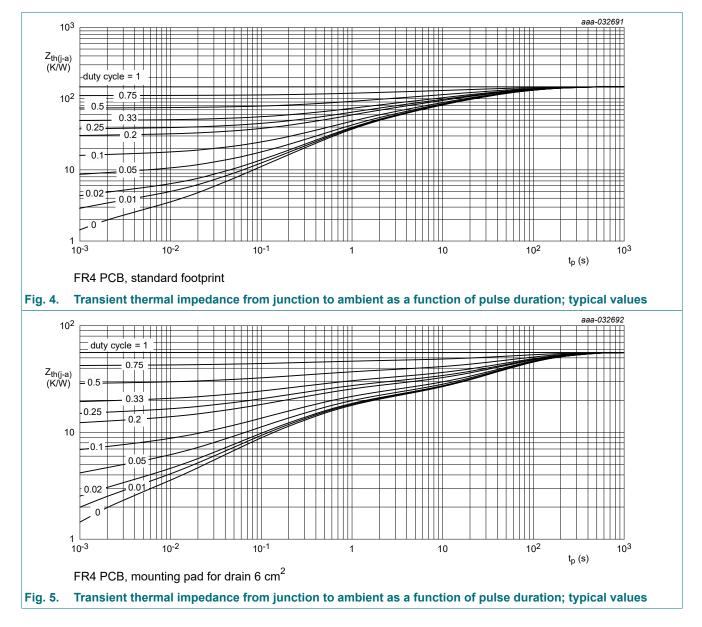


## 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	150	180	K/W
	junction to ambient		[2]	-	55	65	K/W
		in free air; t ≤ 5 s	[2]	-	24	28	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	4	4.8	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

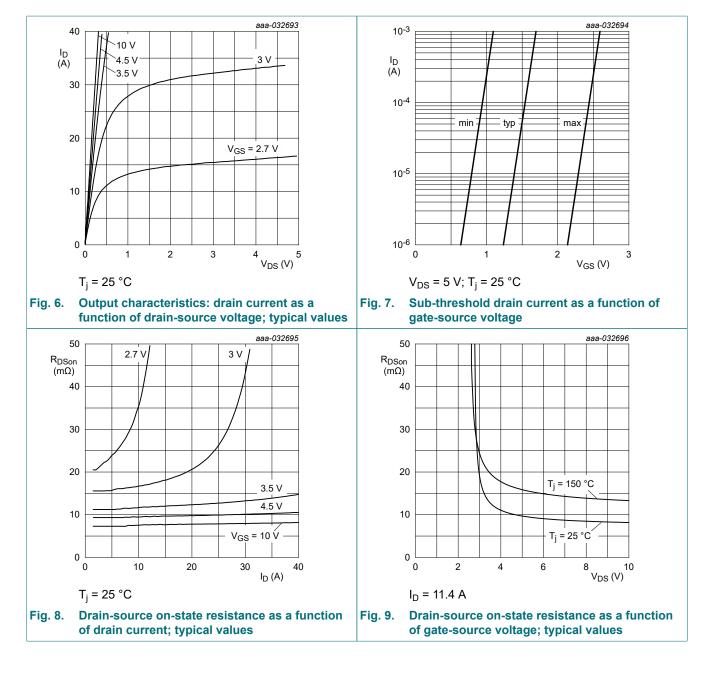
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



# **10. Characteristics**

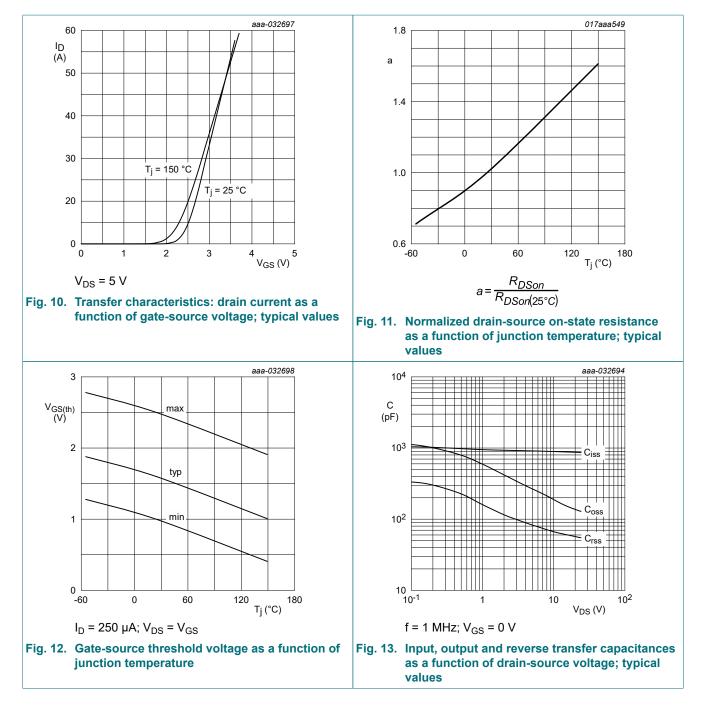
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	30	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	I <sub>D</sub> = 250 μA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C	1	1.6	2.5	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-100	nA
		V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 25 °C	-	7.7	9.1	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 150 °C	-	12.6	14.9	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10.1 A; T <sub>j</sub> = 25 °C	-	9.3	11.6	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz	-	1.7	-	Ω
Dynamic ch	aracteristics	· · · · ·	I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 15 V; I <sub>D</sub> = 11.4 A; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C	-	13.8	20.7	nC
		V <sub>DS</sub> = 15 V; I <sub>D</sub> = 10.1 A; V <sub>GS</sub> = 4.5 V;	-	6.7	10.1	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	2.1	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge		-	1.3	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	0.8	-	nC
Q <sub>GD</sub>	gate-drain charge	1	-	2	-	nC
V <sub>GSpl</sub>	gate-source plateau voltage	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 10.1 A; T <sub>j</sub> = 25 °C	-	2.5	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	865	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	153	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	57	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 10.1 A; V <sub>GS</sub> = 4.5 V;	-	6	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	9	-	ns
t <sub>d(off)</sub>	turn-off delay time	1 [	-	8	-	ns
t <sub>f</sub>	fall time	1	-	4	-	ns
Source-drai	in diode	· · ·				
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 1.7 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.7	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 1.7 A; dI <sub>S</sub> /dt = -100 A/μs;	-	14	-	ns
Q <sub>r</sub>	recovered charge	$V_{GS} = 4.5 \text{ V}; V_{DS} = 15 \text{ V}; T_j = 25 \text{ °C}$	-	6	-	nC
t <sub>a</sub>	reverse recovery rise time	1 [	-	9	-	ns
t <sub>b</sub>	reverse recovery fall time	1	-	5	-	ns

#### 30 V, N-channel Trench MOSFET



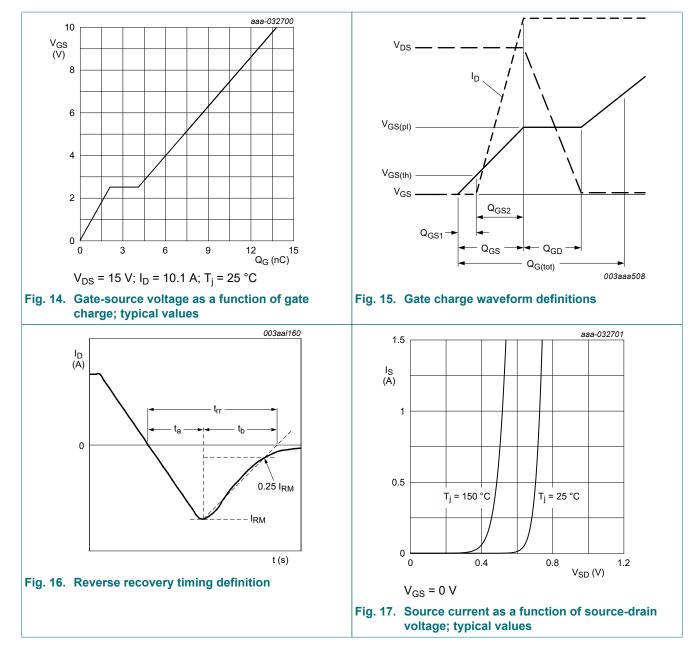
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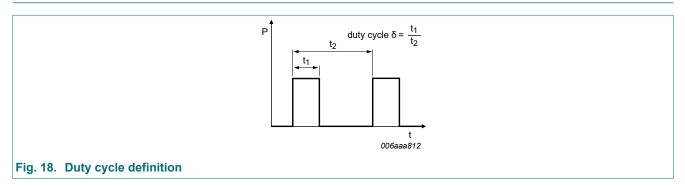


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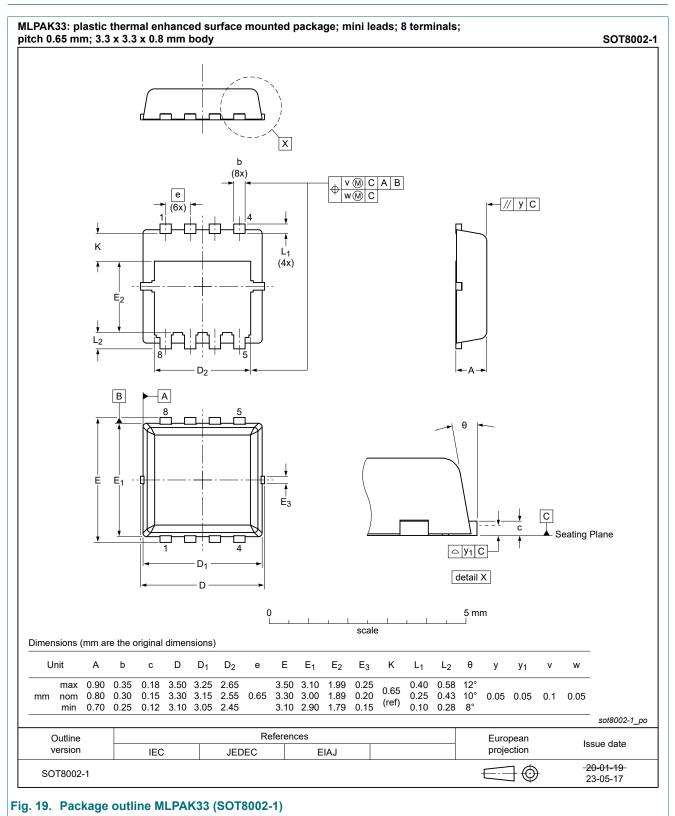
#### 30 V, N-channel Trench MOSFET



## 11. Test information

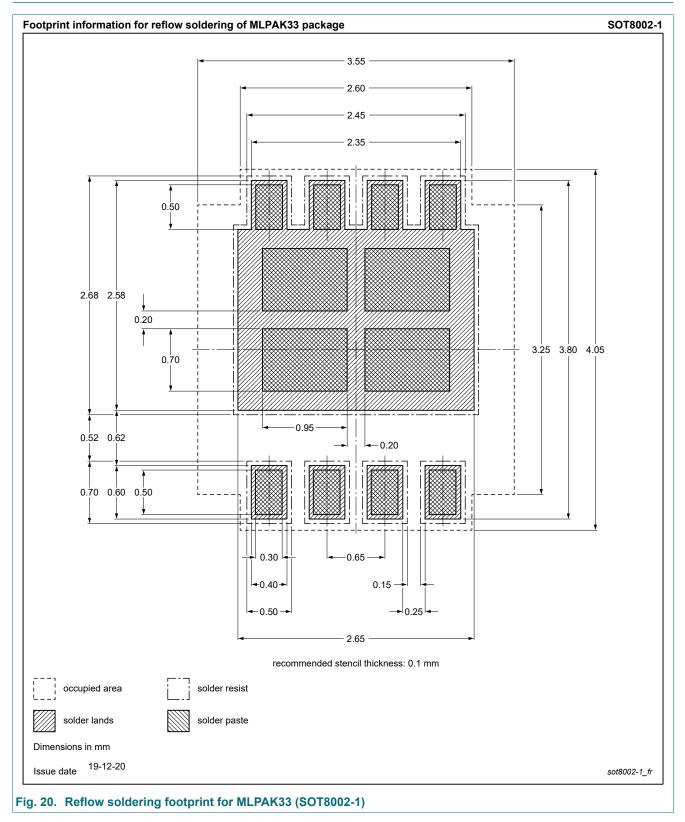


## 12. Package outline



#### 30 V, N-channel Trench MOSFET

## 13. Soldering



# 14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PXN9R0-30QL v.2	20230731	Product data sheet	-	PXN9R0-30QL v.1			
Modifications:	Chapter "Package outline": drawing update						
PXN9R0-30QL v.1	20210105	Product data sheet	-	-			

#### 30 V, N-channel Trench MOSFET

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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